

Electronic Materials: Physics and Applications Jungiao Wu Research Group (2018-2019)

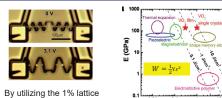
Department of Materials Science and Engineering, University of California, Berkeley Materials Sciences Division, Lawrence Berkeley National Laboratory http://mse.berkelev.edu/~iwu



Introduction

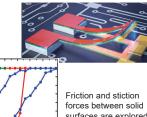
The Wu Group explores fundamental physics and new applications of low-dimensional materials, layered transition metal dichalcogenides (TMDs), strongly correlated materials, and their heterostructures. We aim to understand the influence of defects, doping and external stimuli on the electronic and structural properties and performance of these materials, for potential applications in thermoelectrics, photovoltaics, memory, NEM switches, actuators, infrared sensors, thermal management, etc.

Electromechanical Properties



0.01 expansion in VO2's thermally driven structural phase transition

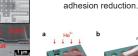
at 67°C, we build micro-actuators and mechanical metamaterials with high energy efficiency and rewritable functionalities



surfaces are explored for nano-electromechanical switches Self-

e (%)

assembled molecular 75 100 125 150 175 200 coating and 2D materials are exploited for

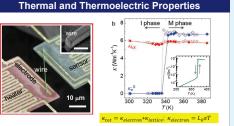


Mechanical, adhesion, friction and elastic properties of TMDs are investigated in response to defects, gating and interlayer coupling.

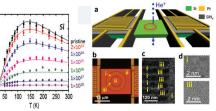
GATE VOLTAGE, Vo (mV)



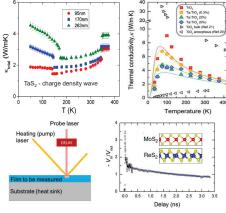
Adv. Mater. 27, 6841 (2015); IEDM, Dec. (2016); Adv. Mater. 26, 1746(2014); Adv. Mater. Int., 3, 1500388 (2016); Nature Comm., 5, 4986 (2014); Nano Lett., 14, 5097 (2014); Small, 14, 1703621 (2018)



Using suspended micro-fabricated devices, thermal, electric and thermoelectric properties of nanowires are measured simultaneously. Shown here is violation of the Wiedemann-Franz law in the metal-insulator transition of VO2.



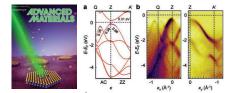
Thermal conductivity and electrical conductivity of blackphosphorus are found to be highly anisotropic in the basal plane: Thermal conductivity of crystalline Si membrane is extremely suppressed by ion irradiation, creating a platform to write programmable thermal metamaterials. Other thermal conduction physics (such as of charge density wave and across phase transition) is being explored.



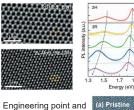
Time-domain thermo-reflectance (TDTR) is used to probe cross-plane thermal conductance of layered materials and thin films of various structures.

Science, 355, 371 (2017); Appl. Phys. Lett., 113, 022103 (2018); Nature Comm., 6, 8573 (2015); Adv. Mater. 27, 3681 (2015); Nano Lett., 14, 4867 (2014); Nano Lett., 14, 2394(2014),





Laser-assisted site-selective annealing, doping, reaction and alloying of new layered materials (eg, black As).

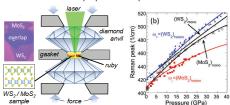


line defects in TMDs for improved materials performance and 4 nm MoS understanding.

Nature Commun. 9, 199 (2018), Nature Commun., 6, 7993 (2015); Nature Physics, 13, 127 (2017); Adv. Mater., 28, 341 (2016); Adv. Mater. 27, 6841 (2015); Nano Lett., 14, 6976 (2014)

High Pressure Modulation

Diamond anvil cells (DAC) are used to apply hydrostatic pressures up to 50 GPa (~ 500k atm); under these pressures, many solid materials exhibit new properties or structures that otherwise do not exist. Optical, Raman, electrical and thermal properties are probed within DAC.

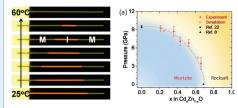


Interlayer coupling in van der Waals heterostructures is modulated to host new properties and stabilize new states

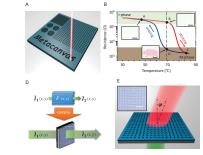
Pressure-tuned physics in 2D materials and structures, such as TMD FETs and graphene/h-BN heterostructures.

Nature Comm. 5, 3252 (2014); Phys. Rev. B, 92, 241408(R)(2015); Phys. Rev. B, 91, 104110 (2015); Nano Lett., 17, 194 (2017)

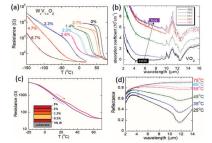
Phase Transitions and Applications



Structural and electronic phase transition in solids are explored in search for new states, effects and applications.



Hysteresis in metal-insulator phase transition in VO2 is exploited for rewritable metamaterials, memories, and optical modulators.

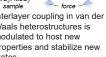


Unprecedented physical properties from doping and graded doping of VO₂ structures enable smart infrared technologies

Nature Chemistry, 6, 151-158 (2014); Adv. Mater., 30, 1703878 (2018); J. Am. Chem. Soc. 135, 4850 (2013); Phys. Rev. Lett., 109, 166406 (2012); Phys. Rev. Lett., 108, 096102 (2012).

Acknowledgments

Work supported by the U. S. National Science Foundation (NSF), Department of Energy (DOE), Singapore-Berkeley Research Initiative of Sustainable Energy (SinBeRISE). Tsinghua-Berkeley Shenzhen Institute (TBSI), Bakar Foundation, and Samsung Inc., etc. Collaborations with local and international colleagues are acknowledged.





Engineering band structures in 2D TMD alloys.

(b) dose=1E13cm